

1ch Gate Driver Providing Galvanic Isolation 2500Vrms Isolation Voltage

BM60051FV-C

General Description

The BM60051FV-C is a gate driver with an isolation voltage of 2500Vrms, I/O delay time of 260ns, minimum input pulse width of 180ns, and incorporates the fault signal output function, under voltage lockout (UVLO) function, short circuit protection (SCP) function, active miller clamping function, temperature monitoring function, switching controller function and output state feedback function.

Features

- Fault signal output function
- ■Under voltage lockout function
- ■Short circuit protection function
- ■Active Miller Clamping
- ■Temperature monitor
- ■Switching controller
- ■Output State Feedback Function
- ■UL1577 Recognized:File No. E356010
- ■AEC-Q100 Qualified (Note 1) (Note 1:Grade1)

Applications

- Automotive isolated IGBT/MOSFET inverter gate drive.
- Automotive DC-DC converter.
- Industrial inverters system.
- UPS system.

Key Specifications

■Isolation Voltage: 2500 [Vrms] (Max)
■Maximum Gate Drive Voltage: 24 [V] (Max)
■I/O Delay Time: 260 [ns] (Max)
■Minimum Input Pulse Width: 180 [ns] (Max)

Packages SSOP-B28W W(Typ) x D(Typ) x H(Max) 9.2mm x 10.4mm x 2.4mm

Typical Application Circuit

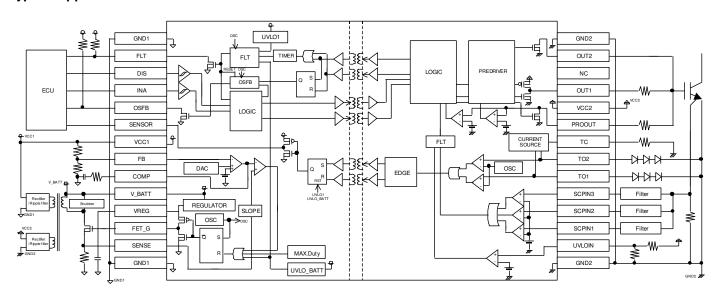


Figure 1. Typical Application Circuit

Recommended Range Of External Constants

Din Nama	Cumbal	Recor	nmended	Linit	
Pin Name	Symbol	Min	Тур	Max	Unit
TC ^(Note2)	Rtc	1.25	-	50	kΩ
TC ^(Note3)	R _{TC}	0.1	1	10	ΜΩ
VBATT	Суватт	3	-	-	μF
VCC1	Cvcc1	0.2	-	-	μF
VCC2	Cvcc2	0.4	-	-	μF
VREG	CVREG	0.1	1	10	μF

(Note2) Use Temperature monitor (Note3) No use Temperature monitor

Pin Configuration (TOP VIEW)

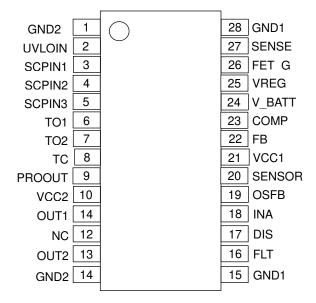


Figure 2. Pin configuration

Pin Descriptions

Pin No.	Pin Name	Function
1	GND2	Output-side ground pin
2	UVLOIN	Output-side UVLO setting pin
3	SCPIN1	Short circuit current detection pin 1
4	SCPIN2	Short circuit current detection pin 2
5	SCPIN3	Short circuit current detection pin 3
6	TO1	Constant current output pin / sensor voltage input pin 1
7	TO2	Constant current output pin / sensor voltage input pin 2
8	TC	Constant current setting resistor connection pin
9	PROOUT	Soft turn-OFF pin /Gate voltage input pin
10	VCC2	Output-side power supply pin
11	OUT1	Output pin
12	NC	No connect
13	OUT2	Output pin for Miller Clamp
14	GND2	Output-side ground pin
15	GND1	Input-side ground pin
16	FLT	Fault output pin
17	DIS	Input enabling signal input pin
18	INA	Control input pin
19	OSFB	Output state feedback output pin
20	SENSOR	Temperature information output pin
21	VCC1	Input-side power supply pin
22	FB	Error amplifier inverting input pin for switching controller
23	COMP	Error amplifier output pin for switching controller
24	V_BATT	Main power supply pin
25	VREG	Power supply pin for driving MOS FET for switching controller
26	FET_G	MOS FET control pin for switching controller
27	SENSE	Current feedback resistor connection pin for switching controller
28	GND1	Input-side ground pin

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Main Power Supply Voltage	V _{BATTMAX}	-0.3 to+40.0 ^(Note 4)	V
Input-Side Control Block Supply Voltage	V _{CC1MAX}	-0.3 to +7.0 ^(Note 4)	V
Output-Side Supply Voltage	V _{CC2MAX}	-0.3 to +30.0 ^(Note 5)	V
INA, DIS Pin Input Voltage	V _{INMAX}	-0.3 to +V _{CC1} +0.3V or +7.0V ^(Note 4)	V
FLT, OSFB Pin Input Voltage	V _{FLTMAX}	-0.3 to +7.0V (Note 4)	V
FLT Pin, OSFB Pin Output Current	I _{FLT}	10	mA
SENSOR Pin Output Current	Isensor	10	mA
FB Pin Input Voltage	V _{FBMAX}	-0.3 to +V _{CC1} +0.3V or +7.0V ^(Note 4)	V
FED_G Pin Output Current (Peak5µs)	IFET_GPEAK	1000	mA
SCPIN1 Pin, SCPIN2 Pin, SCPIN3 Pin Input Voltage	VSCPINMAX	-0.3 to +6.0 ^(Note 5)	٧
UVLOIN Pin Input Voltage	Vuvloinmax	-0.3 to V _{CC2} +0.3 ^(Note 5)	V
TO1 Pin, To2 Pin Input Voltage	V _{TOMAX}	-0.3 to V _{CC2} +0.3 ^(Note 5)	V
TO1 Pin, TO2 Pin Output Current	Ітомах	8	mA
OUT1 Pin Output Current (Peak5µs)	lout1peak	5000 ^(Note 6)	mA
OUT2 Pin Output Current (Peak5µs)	lout2peak	5000 ^(Note 6)	mA
PROOUT Pin Output Current (Peak5µs)	IPROOUTPEAK5	2500 ^(Note 6)	mA
PROOUT Pin Output Current (Peak10µs)	IPROOUTPEAK10	1000 ^(Note 6)	mA
Power Dissipation	Pd	1.12 ^(Note 7)	W
Operating Temperature Range	Topr	-40 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Junction Temperature	Tjmax	+150	°C

(Note 4) Relative to GND1

(Note 5) Relative to GND2

(Note 6) Should not exceed Pd and Tj=150°C

(Note 7) Derate above Ta=25°C at a rate of 9.0mW/°C. Mounted on a glass epoxy of 114.3 mm × 76.2 mm × 1.6 mm.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Units
Main Power Supply Voltage	V _{BATT} (Note 8)	4.5	24.0	V
Input-side Control Block Supply Voltage	V _{CC1} (Note 8)	4.5	5.5	٧
Output-side Supply Voltage	V _{CC2} (Note 9)	9	24	٧
Output side UVLO voltage	V _{UV2TH} (Note 9)	6	-	V

(Note 8) GND1 reference (Note 9) GND2 reference

Insulation Related Characteristics

Parameter	Symbol	Characteristic	Unit
Insulation Resistance (V _{IO} =500V)	Rs	>109	Ω
Insulation Withstand Voltage / 1min	V _{ISO}	2500	Vrms
Insulation Test Voltage / 1sec	V _{ISO}	3000	Vrms

Electrical Characteristics

(Unless otherwise specified Ta=-40°C to125°C, V_{BATT}=5V to 24V, V_{CC1}=4.5V to 5.5V, V_{CC2}=9V to 24V)

Unless otherwise specified Ta=-4 Parameter	Symbol	Min	v, v _{cc1=4.5v} Typ	Max	=9 V to 2	Conditions
General	Syllibol	IVIIII	тур	IVIAX	Offic	Conditions
Main Power Supply	_					FET_G Pin
Circuit Current 1	I _{BATT1}	0.37	0.84	1.47	mA	switching operating
Main Power Supply						FET G Pin
Circuit Current 2	I _{BATT2}	0.34	0.77	1.35	mA	No Switching
Input Side Circuit Current 1	Icc11	0.13	0.31	0.49	mA	OUT=L
Input Side Circuit Current 2	Icc12	0.13	0.31	0.49	mA	OUT=H
Input Side Circuit Current 3	_	0.15	0.42	0.49	mA	INA =10kHZ, Duty=50%
Input Side Circuit Current 4	Icc13	0.23	0.42	0.74		•
	Icc14	2.7	4.7		mA m^	INA =20kHZ, Duty=50%
Output Side Circuit Current	lcc2	2.1	4.7	7.1	mA	Rτc=10kΩ
Switching Power Supply Cont		1.5	F 0	F 5		1 0A(anan)
FET_G Output Voltage H1	V _{FETGH1}	4.5	5.0	5.5	V	I _{OUT} =0A(open)
FET G Output Voltage H2	V _{FETGH2}	4.0	4.5	-	V	V_BATT=4.5V
						I _{OUT} =0A(open)
FET_G Output Voltage L	V _{FETGL}	0	-	0.3	V	I _{OUT} =0A(open)
FET_G ON-Resistance	Rongh	3	6	12	Ω	10mA
(Source-side)	··ONGII			·-		
FET_G ON-Resistance	Rongl	0.3	0.6	1.3	Ω	10mA
(Sink-side)	TIONGE	0.0	0.0	1.0	32	101117
Oscillation Frequency	fosc_sw	80	100	120	kHz	
Soft-start Time	t _{SS}	-	-	50	ms	
FB Pin Threshold Voltage	V _{FB}	1.47	1.50	1.53	V	
FB Pin Input Current	I _{FB}	-0.8	0	+0.8	μΑ	
COMP Pin Sink Current	ICOMPSINK	-160	-80	-40	μΑ	
COMP Pin Source Current	ICOMPSOURCE	40	80	160	μΑ	
V_BATT UVLO OFF Voltage	V _{UVLOBATTH}	4.05	4.25	4.45	V	
V BATT UVLO ON Voltage	V _{UVLOBATTL}	3.95	4.15	4.35	V	
Maximum ON DUTY	Donmax	75	85	95	%	
Logic Block					1	-I
Logic High Level Input Voltage	V _{INH}	0.7×V _{CC1}	-	V _{CC1}	V	INA, DIS
Logic Low Level Input Voltage	VINL	0	-	0.3×V _{CC1}	V	INA, DIS
Logic Pull-Down Resistance	R _{IND}	25	50	100	kΩ	INA
Logic Pull-Up Resistance	RINU	25	50	100	kΩ	DIS
Logic Input Filtering Time	tinfil	80	130	180	ns	INA
DIS Input Filtering Time	TDISFIL	4	10	20	+	IIVA
DIS Input Delay Time		4	10	20	μs	
	t _{DDIS}	4	10	20	μs	
Output						1
OUT1 ON-Resistance	Ronh	0.2	0.55	1.3	Ω	I _{OUT} =40mA
(Source-side) OUT1 ON-Resistance						
(Sink-side)	Ronl	0.2	0.55	1.3	Ω	I _{OUT} =40mA
		F 0			^	V _{CC2} =15V
OUT1 Maximum Current	Гоитмах	5.0	-	-	Α	Guaranteed by design
PROOUT ON-Resistance	Ronpro	0.5	1.2	2.7	Ω	I _{PROOUT} =40mA
Turn ON time	t _{PON}	140	200	260	ns	
Turn OFF time	tpoff	140	200	260	ns	
Propagation Distortion	t _{PDIST}	-60	0	+60	ns	tpoff - tpon
Rise Time	trise	-	30	50	ns	Load=1nF
Fall Time	tfall	-	30	50	ns	Load=1nF
OUT2 ON-Resistance	R _{ON2}	0.4	0.9	2.0	Ω	I _{OUT} =40mA
OUT2 ON Threshold Voltage	V _{OUT2ON}	1.8	2.0	2.2	V	
OUT2 Output Delay Time	t _{оит2он}	-	15	50	ns	
Common Mode Transient Immunity	CM	100	-	-	kV/μs	Design assurance

Electrical Characteristics - continued

(Unless otherwise specified Ta=-40°C to125°C, V_{BATT} =5V to 24V, V_{CC1} =4.5V to 5.5V, V_{CC2} =8V to 24V)

Temperature Monitor	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
TOX PIN Output Frequency	Temperature Monitor			-			
SENSOR Output Druty1 Deshesons 8	TC Pin Voltage	V _{TC}	0.975	1.000	1.025	V	
SENSOR Output Duty1	TOx Pin Output Current	Іто	0.97	1.00	1.03	mA	R _{TC} =10kΩ
SENSOR Output Duty2	SENSOR Output Frequency	fosc_то	8	10	14	kHz	
SENSOR Output Duty3							V _{TOx} =1.35V
TOX Pin Disconnect Detection VTOH 7 8 9 V VIOLIDIAN VIOLIDIAN SENSOR ON Resistance Research -							
Vicility		D _{SENSOR3}	5	10	15	%	V _{TOx} =3.84V
SENSOR ON Resistance Resis	Voltage	V _{ТОН}	7	8	9	V	
Sensor		R _{SENSORH}	-	60	160	Ω	I _{SENSOR} =5mA
Protection Functions Input-side UVLO OFF Voltage Vuv.ont. 3.95 4.15 4.35 V Input-side UVLO Provided Vuv.ont. 2 10 30 μs Input-side UVLO Delay Time (PLT) Input-side UVLO ON Threshold Voltage Vuv.out. 0.85 0.90 0.95 V Investidate UVLO ON Threshold Voltage Input-side UVLO Delay Time (PUT) Input-side UVLO Delay Time (PUT) Input-side UVLO Delay Time (PLT) Input-side UVLO Delay Time (Input-side UVLO Dela		R _{SENSORL}	-	60	160	Ω	I _{SENSOR} =5mA
Input-side UVLO OFF Voltage Vuv.ont A.05 A.25 A.45 V Input-side UVLO ON Voltage Vuv.ont A.95 A.15 A.35 V Input-side UVLO Piltering Time Input-side UVLO Delay Time (OUT) Input-side UVLO Delay Time (OUT) Input-side UVLO Delay Time (OUT) Input-side UVLO Delay Time (FLT) Input-side UVLO Delay Time (FLT) Input-side UVLO Delay Time (FLT) Input-side UVLO OFF Input-side UVLO ON Input-side UVLO Delay Time (Input-side UVLO Delay Time (OUT) Input-side UVLO Delay Time (Input-side UV	,						
Input-side UVLO ON Voltage VuvLo1L 3.95 4.15 4.35 V		V	4.0F	4.05	1 1E	W	
Input-side UVLO Filtering Time LuvLoFilt 2 10 30 μs	•						
Input-side UVLO Delay Time (OUT)							
Input-side UVLO Delay Time Input-side UVLO OFF Input-side UVLO ON Input-side UVLO Delay Time Input-side UVLO	-	t uvlo1fil	2	10	30	μs	
CFLT		tduvlo10ut	2	10	30	μs	
Threshold Voltage	1 '	tduvlo1FLT	2	10	30	μs	
Output-side UVLO ON Threshold Voltage VuvLo2L 0.85 0.90 0.95 V Output-side UVLO Filtering Time (OUT) tuvLo2FIL 2 10 30 μs Output-side UVLO Delay Time (OUT) touvLo2cut 2 10 30 μs Output-side UVLO Delay Time (FLT) touvLo2cut 2 10 30 μs Output-side UVLO Delay Time (FLT) touvLo2cut 2 10 30 μs Output-side UVLO Delay Time (FLT) touvLo2cut 2 10 30 μs Short Current Detection Voltage VSCDET 0.67 0.70 0.73 V Short Current Detection Delay Time (OUT) toscPPIL 0.15 0.30 0.45 μs Short Current Detection Delay Time (PROOUT) toscPPRO 0.17 0.35 0.53 μs PROOUT=30kΩ Pull up Short Turn OFF Release Time FLT Output ON-Resistance TscPFLT 1 - 35 μs Gate State H Detection Threshold Voltage VosFBL 4.5 5.0 5.5 V	''	V _{UVLO2} H	0.95	1.00	1.05	V	
Output-side UVLO tuvLo2Fil. 2 10 30 μs Output-side UVLO Delay Time (OUT) touvLo2oUT 2 10 30 μs Output-side UVLO Delay Time (FLT) touvLo2FLT 3 - 65 μs Short Current Detection Voltage VscDET 0.67 0.70 0.73 V Short Current Detection Filtering Time tscPFIL 0.15 0.30 0.45 μs Short Current Detection Delay time (OUT) tbscPoUT 0.16 0.33 0.50 μs OUT1=30kΩ Pull down Short Current Detection Delay Time (PROOUT) tbscPPRO 0.17 0.35 0.53 μs PROOUT=30kΩ Pull up Short Current Detection Delay Time (FLT) tbscPFLT 1 - 35 μs Short Current Detection Delay Time (FLT) tbscPFLT 1 - 35 μs Short Current Detection Delay Time (FLT) tbscPFLT 1 - 35 μs Short Turn OFF Release Time FLTRLs 20 40 60 ms <	Output-side UVLO ON	V _{UVLO2L}	0.85	0.90	0.95	V	
Filtering Time	-						
Output-side UVLO Delay Time (OUT) touvLozout 2 10 30 μs Output-side UVLO Delay Time (FLT) touvLozeLT 3 - 65 μs Short Current Detection Voltage Vscdet 0.67 0.70 0.73 V Short Current Detection Filtering Time tscPFIL 0.15 0.30 0.45 μs Short Current Detection Delay time (OUT) tbscPout 0.16 0.33 0.50 μs OUT1=30kΩ Pull down Short Current Detection Delay Time (PROOUT) tbscPPRO 0.17 0.35 0.53 μs PROOUT=30kΩ Pull up Short Current Detection Delay Time (PROOUT) tbscPPRO 0.17 0.35 0.53 μs PROOUT=30kΩ Pull up Short Current Detection Delay Time (FLT) tbscPPRO 30 - 110 μs OUT1=30kΩ Pull up Short Current Detection Delay Time (FLT) tbscPPRO 30 - 110 μs OUT1=30kΩ Pull up FLT Output ON-Resistance ReLTL - 30 80 Ω IeLT=5mA <t< td=""><td>•</td><td>tuvlo2fil</td><td>2</td><td>10</td><td>30</td><td>μs</td><td></td></t<>	•	tuvlo2fil	2	10	30	μs	
COUT							
Short Current Detection Voltage VSCDET 0.67 0.70 0.73 V	(OUT)	tduvlo2out	2	10	30	μs	
Voltage	_	t _{DUVLO2FLT}	3	-	65	μs	
Short Current Detection Delay time (OUT) Short Current Detection Delay time (PROOUT) Short Current Detection Delay Time (FLT) Soft Turn OFF Release Time Scoper Soft Turn OFF Release Time Scoper Soft Turn OFF Release Time Soft Turn OFF Release Time Scoper Soft Turn OFF Release Time Soft Turn Off Turn OFF Release Time Soft Turn Off Turn		V _{SCDET}	0.67	0.70	0.73	V	
Short Current Detection		tscpfil	0.15	0.30	0.45	μs	
Short Current Detection	Short Current Detection	toscpout	0.16	0.33	0.50	μs	OUT1=30kΩ Pull down
Short Current Detection	Short Current Detection	toscppro	0.17	0.35	0.53	μs	PROOUT=30kΩ Pull up
Delay Time (FLT) Soft Turn OFF Release Time t _{SCPOFF} 30 - 110 μs OUT1=30kΩ Pull up	Short Current Detection	t _{DSCPFLT}	1	-	35	μѕ	
FLT Output ON-Resistance						· .	OUT4 OC 5 5 "
Fault Output Holding Time t _{FLTRLS} 20 40 60 ms Gate State H Detection Threshold Voltage VOSFBH 4.5 5.0 5.5 V Gate State L Detection Threshold Voltage VOSFBL 4.0 4.5 5.0 V OSFB Output Filtering Time tosfbfil 1.5 2.0 2.5 μs OSFB Output ON-Resistance Rosfb - 30 80 Ω Iosfb=5mA			30	-		'	'
Gate State H Detection VOSFBH 4.5 5.0 5.5 V Threshold Voltage VOSFBL 4.0 4.5 5.0 V Gate State L Detection Threshold Voltage VOSFBL 4.0 4.5 5.0 V OSFB Output Filtering Time tosfbril 1.5 2.0 2.5 μs OSFB Output ON-Resistance Rosfb - 30 80 Ω Iosfb=5mA			-				I _{FLT} =5mA
Threshold Voltage Gate State L Detection Threshold Voltage OSFB Output Filtering Time OSFB Output ON-Resistance RosfB VosfBH 4.5 5.0 V 4.5 5.0 V V V Institute of the control of the contr		t _{FLTRLS}	20	40	60	ms	
Threshold Voltage Gate State L Detection Threshold Voltage OSFB Output Filtering Time OSFB Output ON-Resistance RosfB - 30 80 Ω Iosfb=5mA		V_{OSFBH}	4.5	5.0	5.5	V	
Threshold Voltage OSFB Output Filtering Time OSFB Output ON-Resistance RosFB - 30 V V V V V V LosFB=5mA		23.2	_	_	_	1	
OSFB Output Filtering Time tosfbfil 1.5 2.0 2.5 μs OSFB Output ON-Resistance Rosfb - 30 80 Ω losfb=5mA		Vosfbl	4.0	4.5	5.0	V	
OSFB Output ON-Resistance RosFB - 30 80 Ω IoSFB=5mA	-	tosfbfil	1.5	2.0	2.5	μs	
			-			•	I _{OSFB} =5mA
Out Discussing Time LOSEBELS 20 40 00 1115	OSFB Output Holding Time	tosfbrls	20	40	60	ms	

UL1577 Ratings TableFollowing values are described in UL Report.

Parameter	Values	Units	Conditions
Side 1 (Input Side) Circuit Current	1.37	mA	V_BATT=14V,VCC1=5.0V,OUT1=L
Side 2 (Output Side) Circuit Current	4.7	mA	VCC2=15V, OUT1=L
Side 1 (Input Side) Consumption Power	14.4	mW	V_BATT=14V,VCC1=5.0V,OUT1=L
Side 2 (Output Side) Consumption Power	70.5	mW	VCC2=15V, OUT1=L
Isolation Voltage	2500	Vrms	
Maximum Operating (Ambient) Temperature	125	°C	
Maximum Junction Temperature	150	°C	
Maximum Strage Temperature	150	°C	
Maximum Data Transmission Rate	2.7	MHz	

Typical Performance Curves

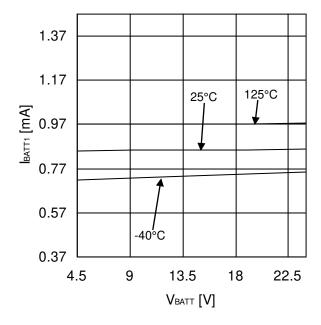


Figure 3. Main Power SupplyCircuit Current 1 (FET_G Pin switching operating)

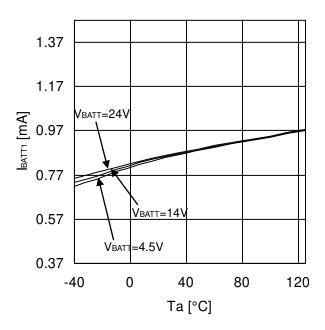


Figure 4. Main Power SupplyCircuit Current 1 (FET_G Pin switching operating)

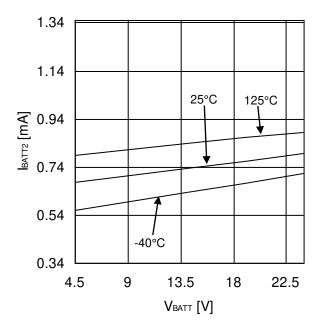


Figure 5. Main Power SupplyCircuit Current 2 (FET_G Pin no switching)

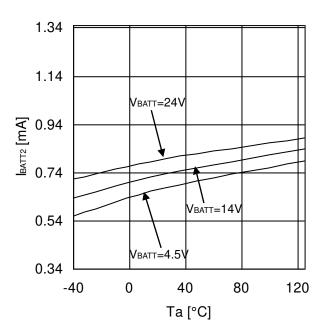


Figure 6. Main Power SupplyCircuit Current 2 (FET_G Pin no switching)

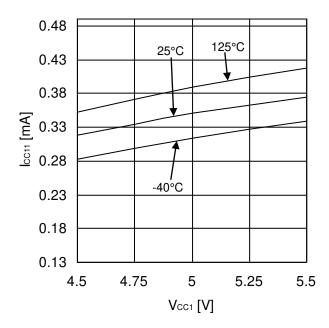


Figure 7. Input Side Circuit Current 1 (OUT1=L)

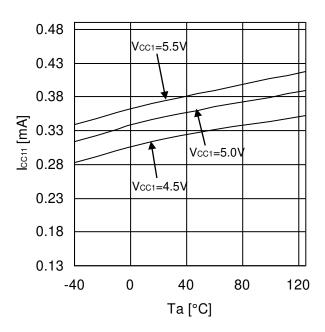


Figure 8. Input Side Circuit Current 1 (OUT1=L)

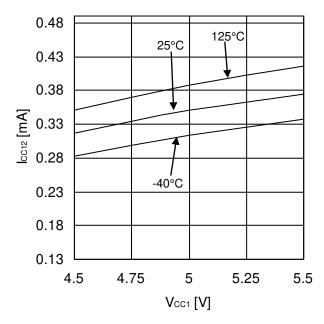


Figure 9. Input Side Circuit Current 2 (OUT1=H)

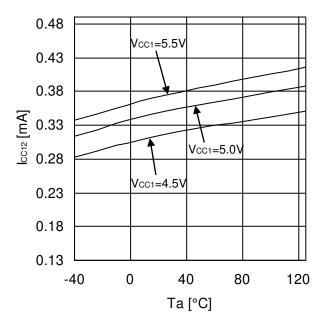


Figure 10. Input Side Circuit Current 2 (OUT1=H)

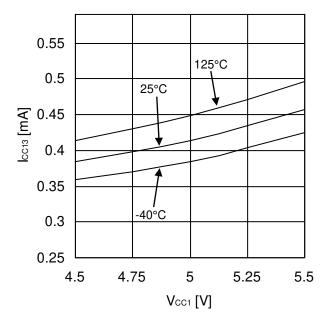


Figure 11. Input Side Circuit Current 3 (INA=10kHz, Duty=50%)

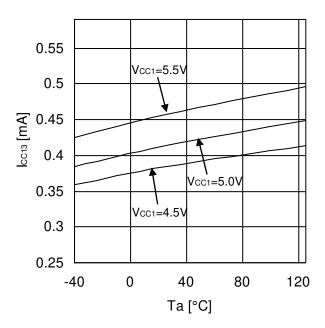


Figure 12. Input Side Circuit Current 3 (INA=10kHz, Duty=50%)

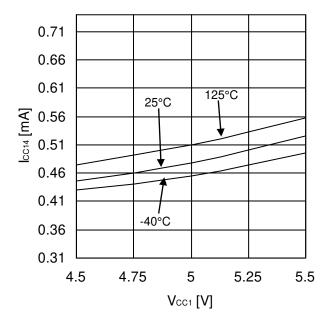


Figure 13. Input Side Circuit Current 4 (INA=20kHz, Duty=50%)

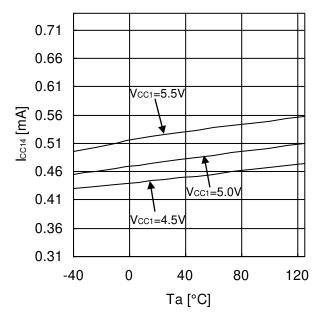


Figure 14. Input Side Circuit Current 4 (INA=20kHz, Duty=50%)

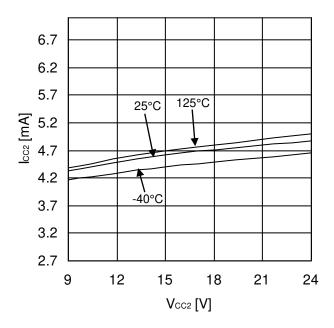


Figure 15. Output Side Circuit Current (OUT=L, R_{TC} =10 $k\Omega$)

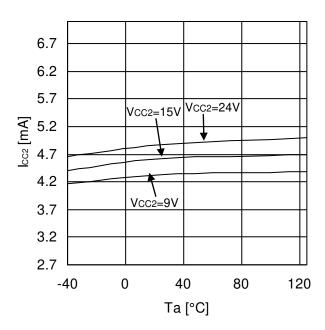


Figure 16. Output Side Circuit Current (OUT=L, $RTc=10k\Omega$)

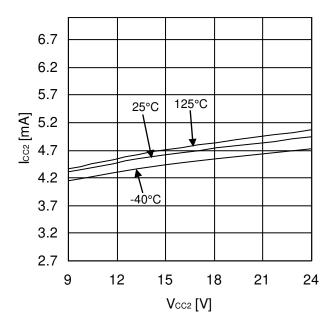


Figure 17. Output Side Circuit Current (OUT=H, $RTc=10k\Omega$)

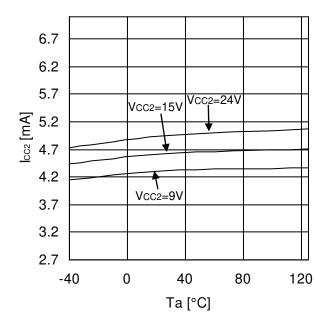


Figure 18. Output Side Circuit Current (OUT=H, $RTc=10k\Omega$)

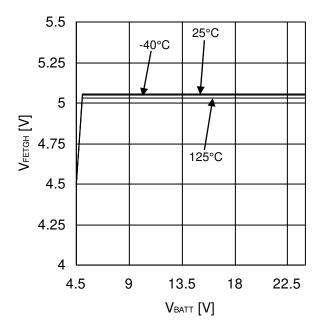


Figure 19. FET_G Output Voltage H1/H2

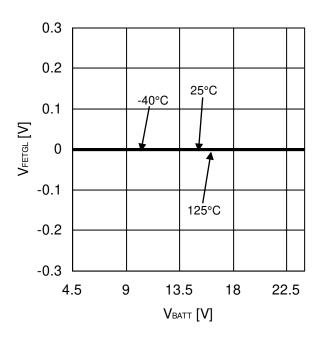


Figure 20. FET_G Output Voltage L

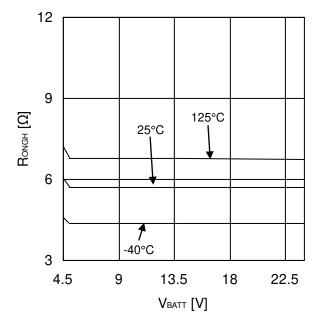


Figure 21. FET_G ON-Resistance (Source-side)

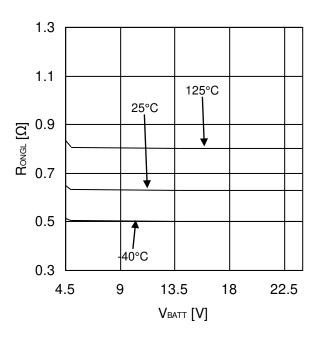


Figure 22. FET_G ON-Resistance (Sink-side)

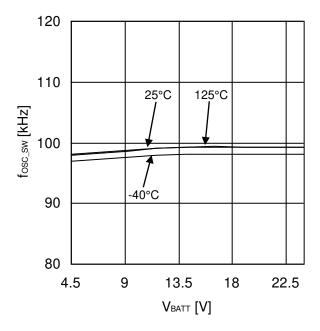


Figure 23. Oscillation Frequency

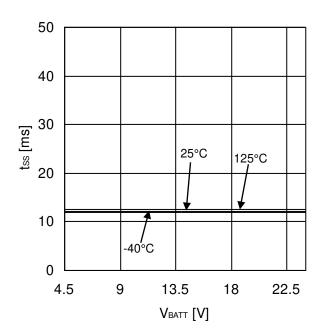


Figure 24. Soft-start Time

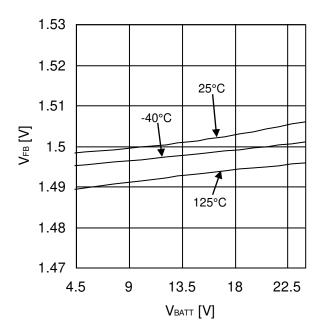


Figure 25. FB Pin Threshold Voltage

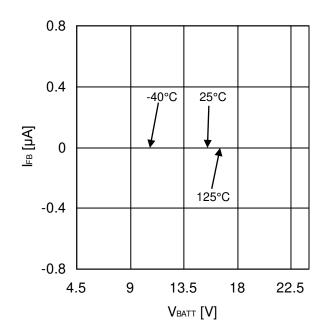


Figure 26. FB Pin Input Current

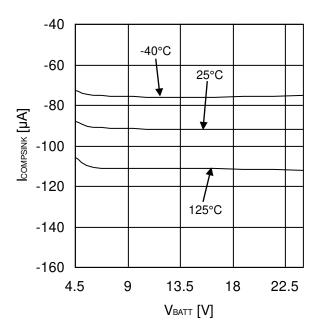


Figure 27. COMP COMP Pin Sink Current

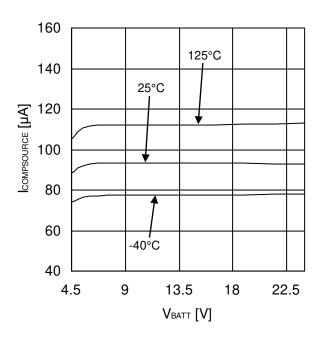


Figure 28. COMP Pin Source Current

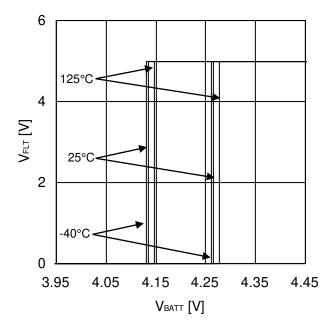


Figure 29. V_BATT UVLO ON/OFFVoltage

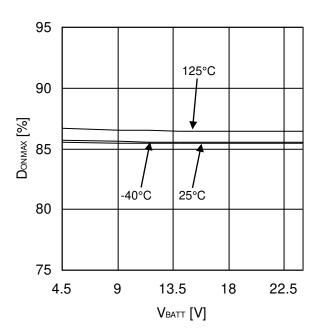


Figure 30. Maximum ON DUTY

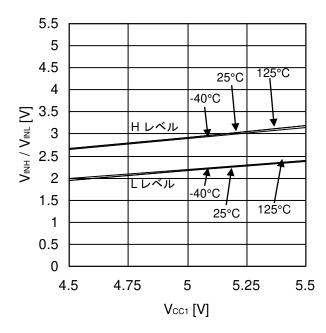


Figure 31. Logic High / Low Level Input Voltage (INA, DIS)

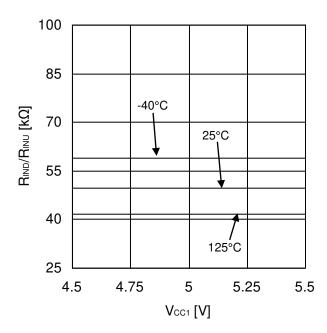


Figure 32. Logic Pull-Down Resistance (INA) Pull-Up Resistance (DIS)

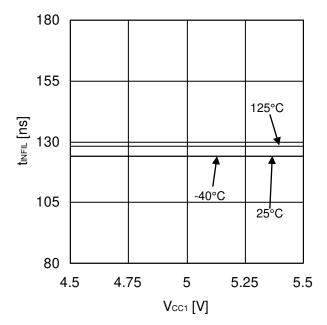


Figure 33. Logic Input Filtering Time (L pulse)

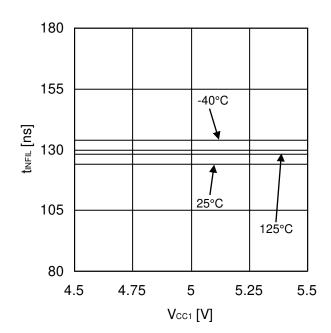


Figure 34. Logic Input Filtering Time (H pulse)

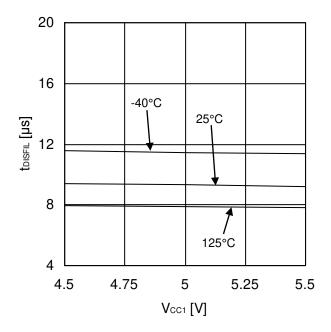


Figure 35. DIS Input Filtering Time

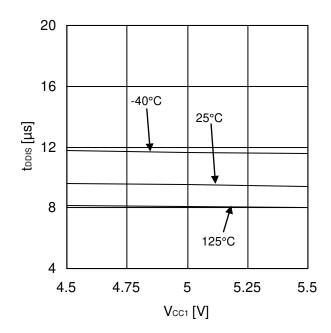


Figure 36. DIS Input Delay Time

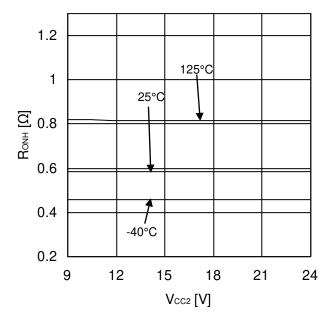


Figure 37. OUT1 ON-Resistance(Source-side) (Iout1=40mA)

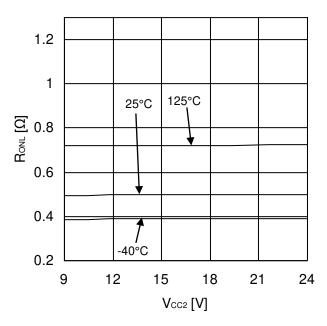


Figure 38. OUT1 ON-Resistance (Sink-side) (Iout1=40mA)

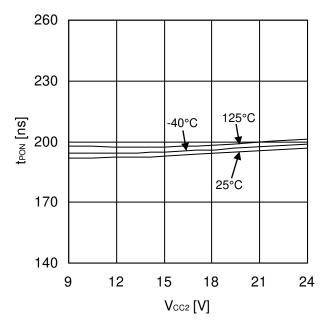


Figure 39. Turn ON time

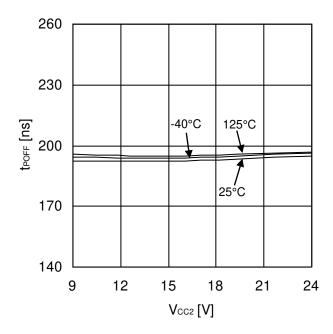


Figure 40. Turn OFF time

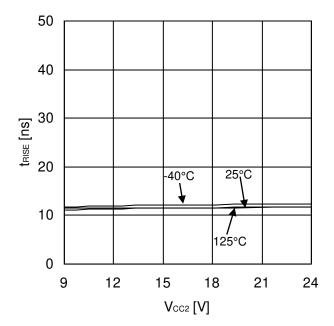


Figure 41. Rise time

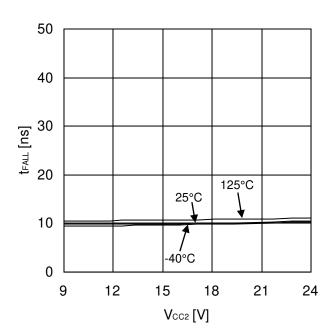
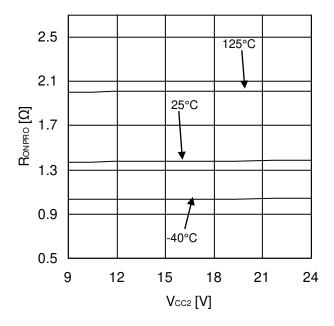
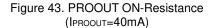


Figure 42. Fall time





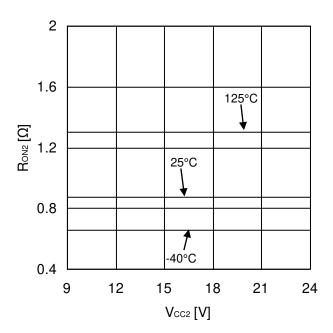


Figure 44. OUT2 ON-Resistance (IOUT2=40mA)

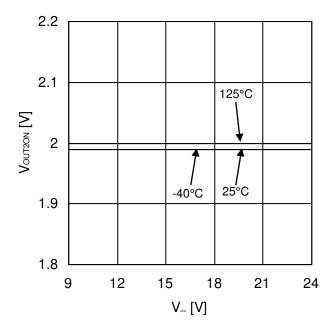


Figure 45. OUT2 ON Threshold Voltage

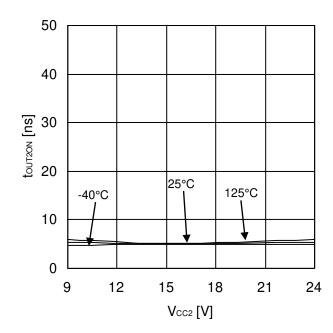


Figure 46. OUT2 Output Delay Time

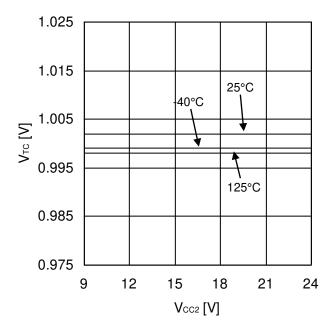


Figure 47. TC Pin Voltage

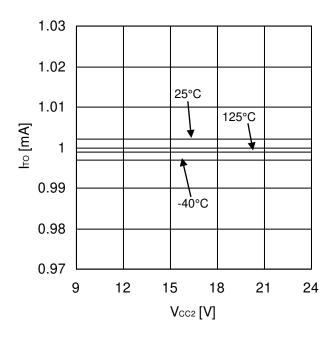


Figure 48. TOx Pin Output Current (RTC=10kΩ)

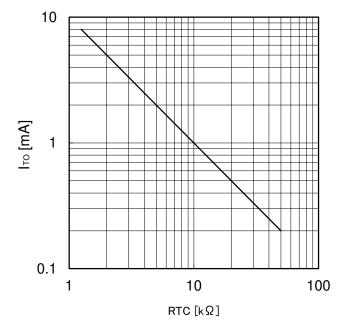


Figure 49. TOx Pin Output Current

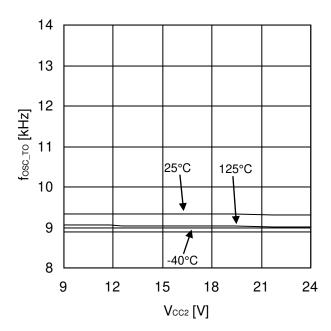


Figure 50. SENSOR Output Frequency

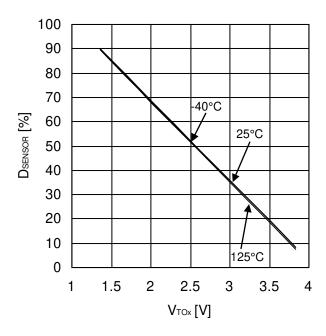


Figure 51. SENSOR Output Duty

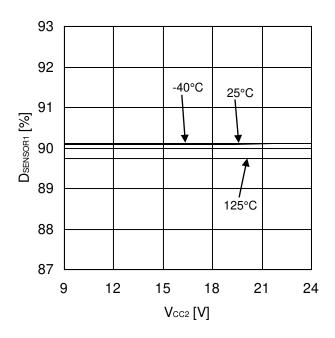


Figure 52. SENSOR Output Duty1 (VTOx=1.35V)

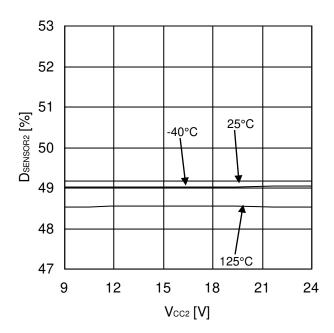


Figure 53. SENSOR Output Duty2 (VTOx=2.59V)

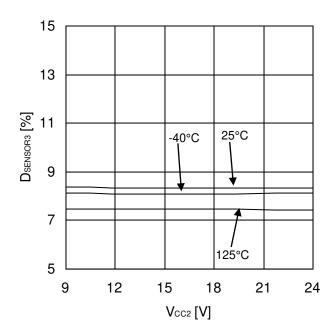


Figure 54. SENSOR Output Duty3 (VTOx=3.84V)

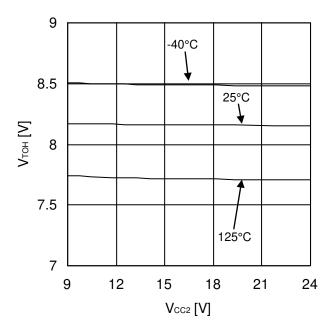


Figure 55. TOx Pin Disconnect Detection Voltage

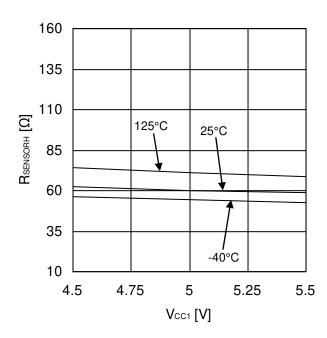


Figure 56. SENSOR ON Resistance(Source-side) (ISEBSOR=5mA)

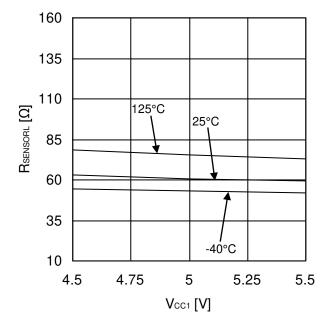


Figure 57. SENSOR ON Resistance (Sink-side) (Isensor=5mA)

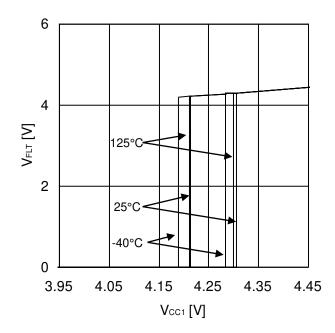


Figure 58. Input-side UVLO ON/OFF Voltage

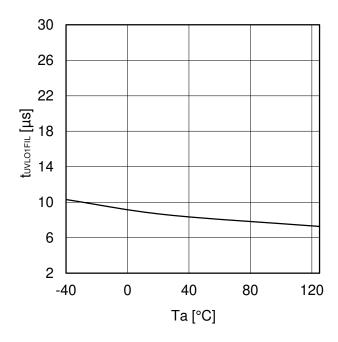


Figure 59. Input-side UVLO Filtering Time

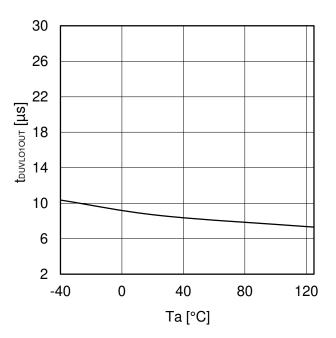


Figure 60. Input-side UVLO Delay Time (OUT1)

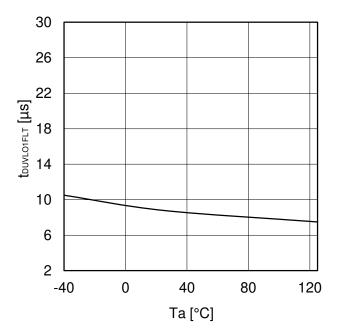


Figure 61. Input-side UVLO Delay Time (FLT)

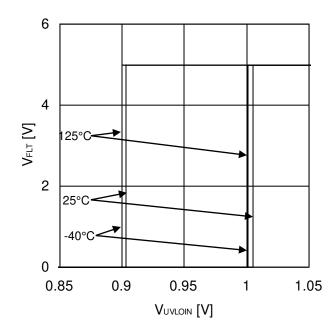


Figure 62. Output-side UVLO ON / OFF Threshold Voltage

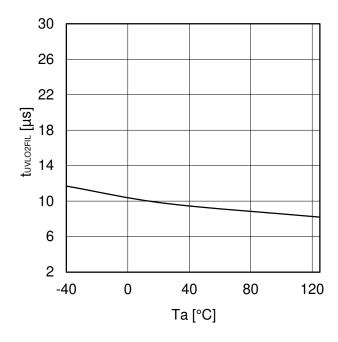


Figure 63. Output-side UVLO Filtering Time

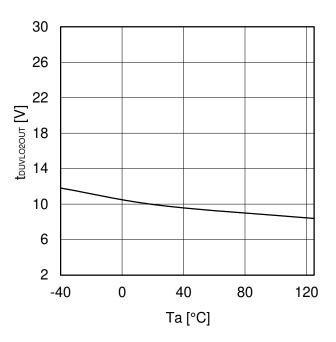


Figure 64. Output-side UVLO Delay Time (OUT1)

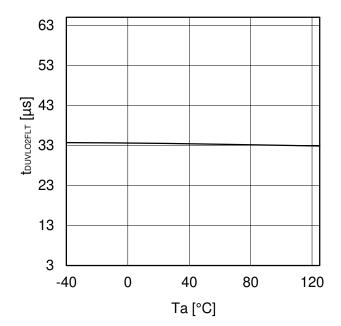


Figure 65. Output-side UVLO Delay Time (FLT)

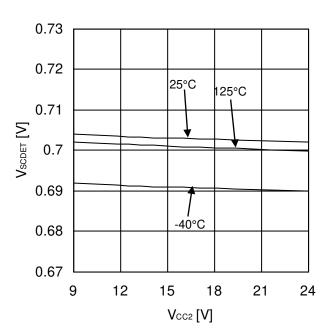
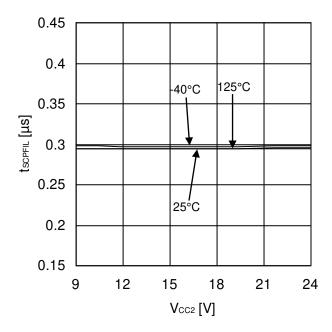


Figure 66. Short Current Detection Voltage





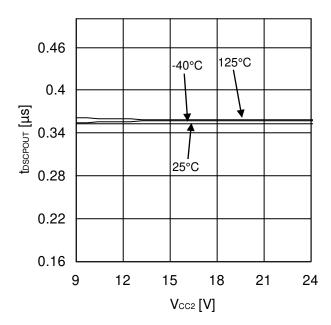


Figure 68. Short Current Detection Delay time (OUT1)

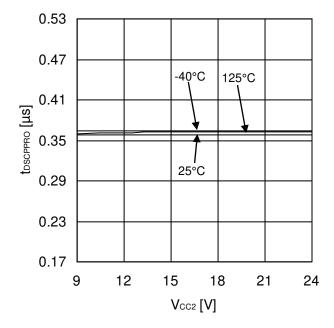


Figure 69. Short Current Detection Delay time (PROOUT)

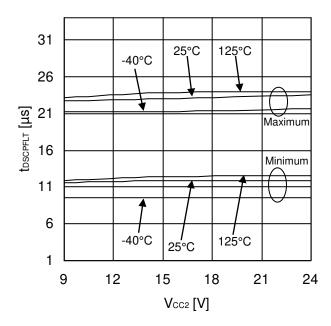


Figure 70. Short Current Detection Delay time (FLT)

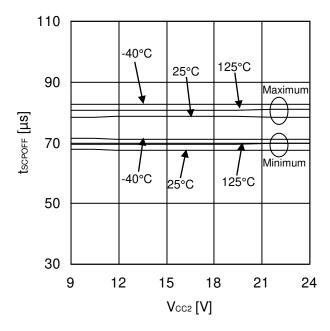


Figure 71. Soft Turn OFF Release Time

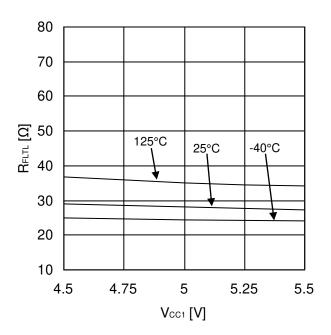


Figure 72. FLT Output ON-Resistance (IFLT=5mA)

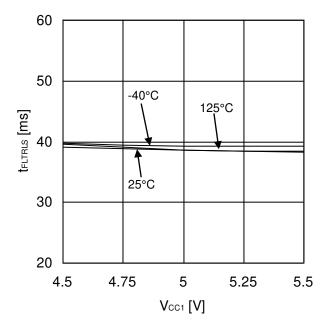


Figure 73. Fault Output Holding Time

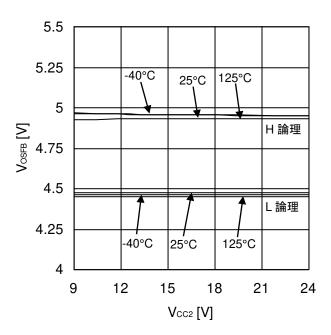


Figure 74. Gate State H /L Detection Threshold Voltage

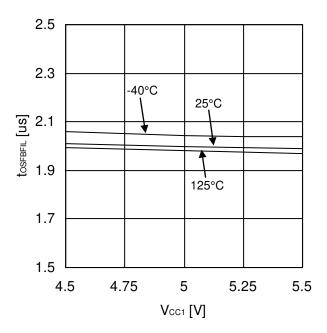


Figure 75. OSFB Output Filtering Time

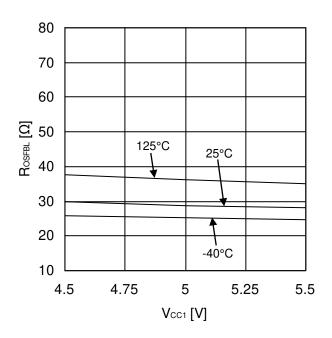


Figure 76. OSFB Output ON-Resistance (Iosfb=5mA)

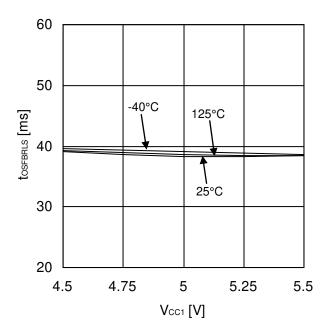


Figure 77. OSFB Output Holding Time

Description of Pins and Cautions on Layout of Board

1. V BATT (Main power supply pin)

This is the main power supply pin. Connect a bypass capacitor between V_BATT and GND1 in order to suppress voltage variations. Be sure to apply a power supply even when the switching power supply is not used, since the internal reference voltage of the input side chip is generated from this power supply.

2. VCC1 (Input-side power supply pin)

The VCC1 pin is a power supply pin on the input side. To suppress voltage fluctuations due to the driving current of the internal transformer, connect a bypass capacitor between the VCC1 and the GND1 pins.

3. GND1 (Input-side ground pin)

The GND1 pin is a ground pin on the input side.

4. VCC2 (Output-side positive power supply pin)

The VCC2 pin is a positive power supply pin on the output side. To reduce voltage fluctuations due to the driving current of the internal transformer and output current, connect a bypass capacitor between the VCC2 and the GND2 pins.

5. GND2 (Output-side ground pin)

The GND2 pin is a ground pin on the output side. Connect the GND2 pin to the emitter / source of output device.

6. INA, DIS (Control input pin, input enabling signal input pin)

They are pins for deciding the output logic.

DIS	INA	OUT1
Н	Х	L
L	L	L
L	Н	Н

X: Don't care

7. FLT (Fault output pin)

The FLT pin is an open drain pin that outputs a fault signal when a fault occurs (i.e., when the under voltage lockout function (UVLO) or short circuit protection function (SCP) is activated).

State	FLT
While in normal operation	Hi-Z
When a Fault occurs (UVLO / SCP)	L

8. OSFB (Output pin for monitoring gate condition)

This is an open drain pin which compares gate logic of the output element monitored with PROOUT pin and DIS/INA pin

input logic, and outputs L when they disaccord.

Status	DIS	INA	PROOUT(input)	OSFB
	Н	Х	Н	L
	Н	X	L	Hi-Z
Normal aparation	L	L	Н	L
Normal operation	L	L	L	Hi-Z
	L	Н	Н	Hi-Z
	L	Н	L	L
Fault	X	Х	X	Hi-Z

X: Don't care

9. SENSOR (Temperature information output pin)

This is a pin which outputs the voltage of either TO1 or TO2, whichever is lower, converted to Duty cycle.

10. FB (Error amplifier inverting input pin for switching controller)

This is a voltage feedback pin of the switching controller. Connect it to VCC1 when the switching controller is not used.

11. COMP (Error amplifier output pin for switching controller)

This is the gain control pin of the switching controller. Connect a phase compensation capacitor and resistor. When the switching controller is not used, connect it to GND1.

12. VREG (Power supply pin for the driving MOS FET of the switching controller)

This is the power supply pin for the driving MOSFET of the switching controller transformer drive. Be sure to connect a capacitor between VREG and GND1 even when the switching controller is not used, in order to prevent oscillation and suppress voltage variation due to FET_G output current.

Description of Pins and Cautions on Layout of Board - continued

13. FET G (MOS FET control pin for switching controller)

This is a MOSFET control pin for the switching controller transformer drive. Leave it unconnected when the switching controller is not used.

14. SENSE (Connection to the current feedback resistor of the switching controller)

This is a pin connected to the resistor of the switching controller current feedback. FET_G pin output duty is controlled by the voltage value of this pin. Connect it to VCC1 when switching controller is not used.

15. OUT(Output pin)

The OUT pin is a gate driving pin.

16. OUT2 (Miller clamp pin)

This is the miller clamp pin for preventing a rise of gate voltage due to miller current of output element connected to OUT1. OUT2 should be unconnected when miller clamp function is not used.

17. PROOUT (Soft turn-OFF pin)

This is a pin for soft turn-OFF of output pin when short-circuit protection is in action. It also functions as a pin for monitoring gate voltage for miller clamp function and output state feedback function.

18. SCPIN1, SCPIN2, SCPIN3 (Short circuit current detection pin)

These are the pins used to detect current for short circuit protection. When the SCPIN1 pin, SCPIN2 pin or SCPIN3 pin voltage exceeds the voltage set with the V_{SCDET} parameter, the SCP function will be activated, this will make the IC function in an open state. To avoid such trouble, connect a resistor between the SCPIN and the GND2 or short the SCPIN pin to GND2 when the SCP function is not used.

19. TC (Resistor connection pin for setting constant current source output)

The TC pin is a resistor connection pin for setting the constant current output. If an arbitrary resistance value is connected between TC and GND2, it is possible to set the constant current value output from TO.

20. TO1, TO2 (Constant current output / sensor voltage input pin)

The TO1 pin and the TO2 pin are constant current output / voltage input pins. It can be used as a sensor input by connecting an element with arbitrary impedance between TOx pin and GND. Furthermore, the TOx pin disconnect detection function is built-in.

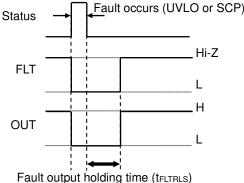
21. UVLOIN (Output-side UVLO setting input pin)

The UVLOIN pin is a pin for deciding UVLO setting value of VCC2. The threshold value of UVLO can be set by dividing the resistance voltage of VCC2 and inputting such value.

1. Fault status output

This function is used to output a fault signal from the FLT pin when a fault occurs (i.e., when the under voltage lockout function (UVLO) or short circuit protection function (SCP) is activated) and hold the fault signal until fault output holding time (tfltrls) is completed.

Status	FLT pin
Normal	Hi-Z
Fault occurs	L



r dant batpat moraling time (ti zimzo)

Figure 78. Fault Status Output Timing Chart

2. Under voltage Lockout (UVLO) function

The BM60051FV-C incorporates the under voltage lockout (UVLO) function on V_BATT, VCC1 and VCC2. When the power supply voltage drops to the UVLO ON voltage, the OUT pin and the FLT pin will both output the "L" signal. When the power supply voltage rises to the UVLO OFF voltage, these pins will be reset. However, during the fault output holding time set in "Fault status output" section, the OUT pin and the FLT pin will hold the "L" signal. In addition, to prevent mis-triggers due to noise, mask time tuvlo1FIL and tuvlo2FIL are set on both low and high voltage sides.

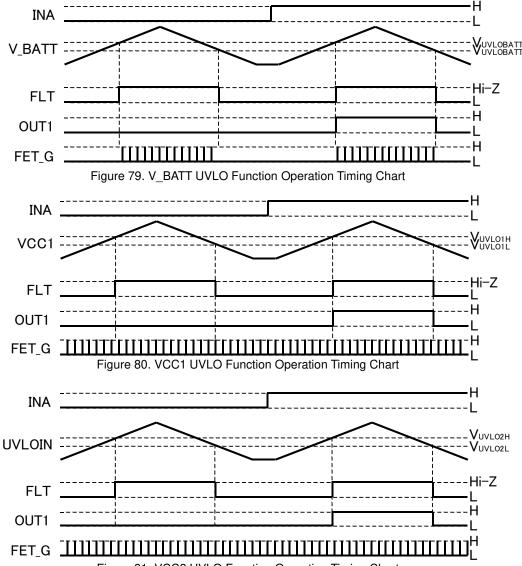


Figure 81. VCC2 UVLO Function Operation Timing Chart

3. Short circuit protection (SCP) function

When the SCPIN pin voltage exceeds a voltage set with the V_{SCDET} parameter, the SCP function will be activated. When the SCP function is activated, the OUT pin voltage will be set to the "Hi-Z" level and the PROOUT pin voltage will go to the "L" level first (soft turn-OFF).Next, when the short-circuit current falls below the threshold value and after t_{SCPOFF} has passed, OUT pin and PROOUT pin become L. Finally, when the fault output holding time is completed, the SCP function will be released.

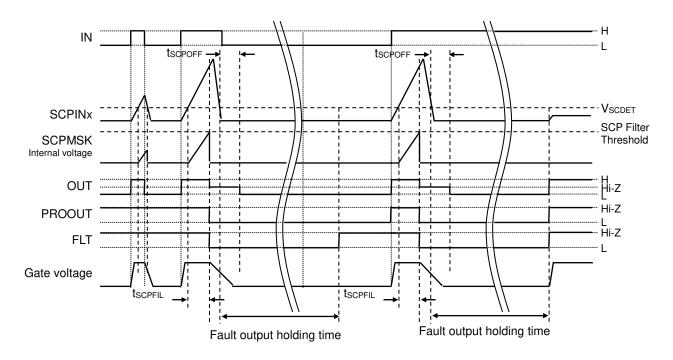


Figure 82. SCP Operation Timing Chart

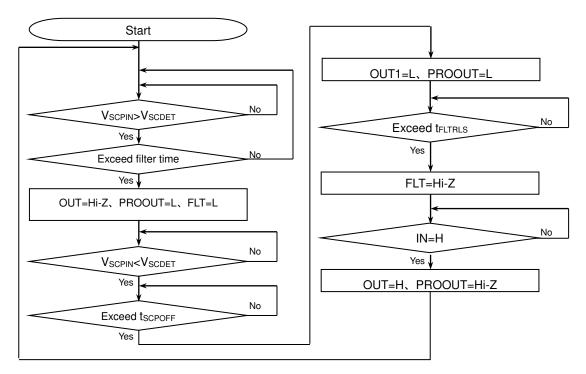


Figure 83. SCP Operation Status Transition Diagram

4. Miller Clamp function

When OUT1=L and PROOUT pin voltage < V_{OUT2ON}, internal MOS of OUT2 pin is turned ON, and miller clamp function operates. While the short-circuit protection function is activated, miller clamp function operates after lapse of soft turn-OFF release time t_{SCPOFF}.

Short current	SCPIN	INA	PROOUT	OUT2		
Detected	Not less than V _{SCDET}	Х	Х	Hi-Z		
Not detected	Х	L	Not less than VOUT2ON	Hi-Z		
	×	L	Not more than VOUT2ON	L		
	X	Н	X	Hi-Z		

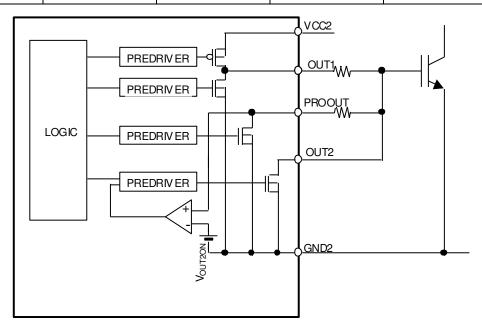


Figure 84. Block Diagram of Miller Clamp Function

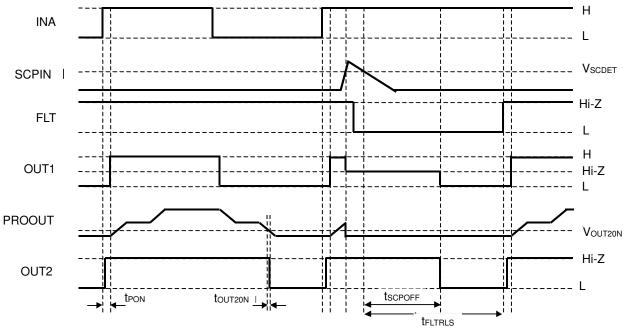


Figure 85. Timing chart of Miller Clamp Function

5. Temperature monitor function

Constant current is supplied from TOx pins from the built-in constant current circuit. This current value can be adjusted in accordance with the resistance value connected between TC and GND2. Furthermore, TO_X pin has voltage input function, and outputs signal of TOx pin voltage converted to Duty from SENSOR pin. When voltage of either one of TO_X pins is no less than disconnect detection voltage V_{TOH} , SENSOR pin outputs L. Therefore, when only one of the TO_X pins is used, connect a resistor between the other TO pins and GND2 to keep pin voltage at no more than V_{TOH} .

$$\text{Constant current value } = \frac{V_{\text{TC}} \times 10}{R_{\text{TC}}}$$

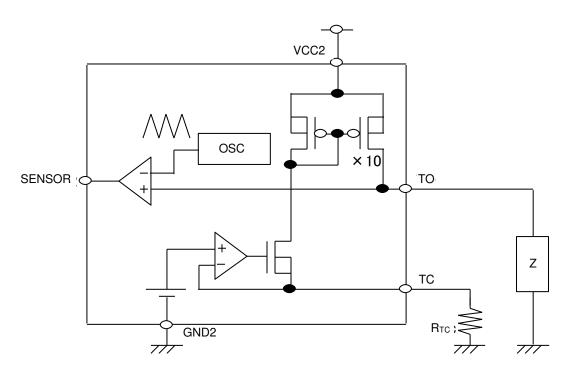
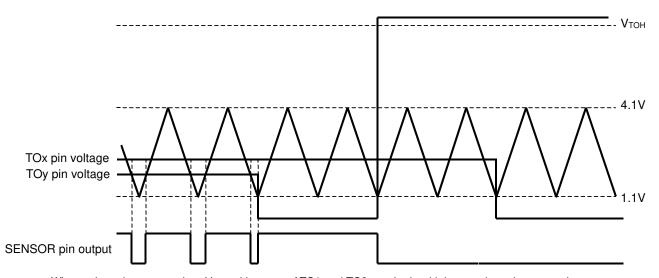


Figure 86. Block Diagram of Temperature Monitor Function



When voltage is no more than V_{TOH} , either one of TO1 and TO2 terminals with lower voltage has precedence.

Figure 87. Timing Chart of Temperature Monitor Function

Connect to VCC1

Description of Functions and Examples of Constant Setting - continued

6. Switching regulator

(1) Basic action

This IC has a built-in switching power supply controller which repeats ON/OFF synchronizing with internal clock. When VBATT voltage is supplied (VBATT > VUVLOBATTH), FTE_G pin starts switching by soft-start. Output voltage is determined by the following equation by external resistance and winding ratio "n" of flyback transformer (n= VOUT2 side winding number/VOUT1 side winding number)

$$V_{OUT2} = V_{FB} \times \{ (R_1 + R_2) / R_2 \} \times n[V]$$

(2) MAX DUTY

When, for example, output load is large, and voltage level of SENSE pin does not reach current detection level, output is forcibly turned OFF by Maximum On Duty (Donmax).

(3) Pinconditions when the switching power supply controller is not used Implement pin treatment as shown below when switching power supply is not used.

Treatment Method Pin Number Pin Name FΒ 22 Connect to VCC1 23 **COMP** Connect to GND1 24 V_BATT Connect power supply 25 **VREG** Connect capacitor FET_G 26 No connection

SENSE

7. Gate state monitoring function

27

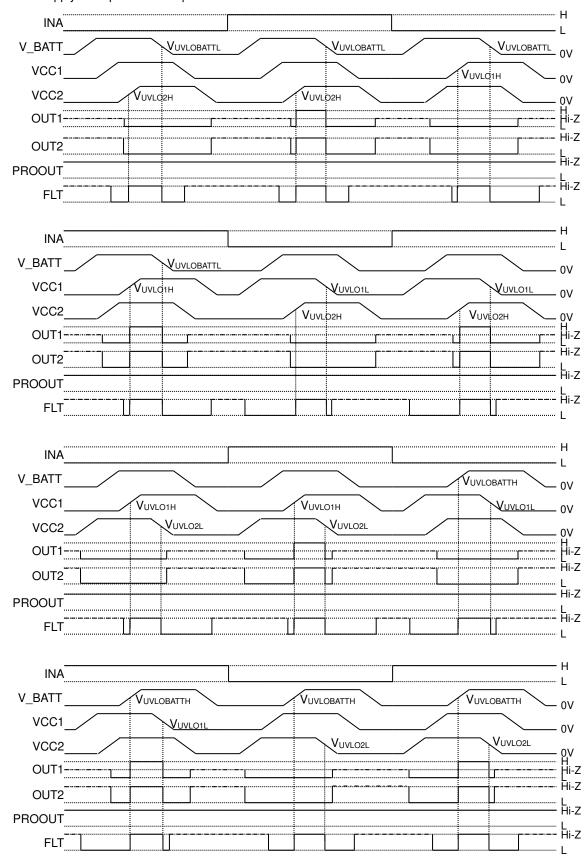
When gate logic and input logic of output device monitored with PROOUT pin are compared, a logic L is output from OSFB pin when they disaccord. In order to prevent the detection error due to delay of input and output, OSFB filter time tosfbon is provided.

Description of Functions and Examples of Constant Setting - continued 8. _ I/O condition table

	dition table	Input						Output					
No.	No. Status	VCC1	UVLOIN	VBATT	SCPINX	D I S	- Z A	PROOUT	O U T 1	O U T 2	PROOUT	FLT	O S F B
1	SCP	0	Н	0	Н	L	Н	Χ	Z	Z	L	L	Z
2	- VCC1UVLO	UVLO	X	Χ	L	Χ	Χ	Н	L	Z	Z	L	Z
3		UVLO	X	X	L	Χ	Χ	L	L	L	Z	L	Z
4	VCC2UVLO	X	L	Χ	L	Χ	Χ	Н	L	Z	Z	L	Z
5	VCC20VLC	X	L	X	L	Χ	Χ	L	L	L	Z	L	Z
6	VBATT1UVLO	X	Х	UVLO	L	Χ	Χ	Н	L	Z	Z	L	Z
7	VBATTTOVLO	Χ	X	UVLO	L	Χ	Χ	L	L	L	Z	L	Z
8	Disable	0	Н	0	L	Η	Χ	Н	L	Z	Z	Z	L
9	Disable	0	Н	0	L	Н	Χ	L	L	L	Z	Z	Z
10	Normal Operation L Input	0	Н	0	L	L	L	Н	L	Z	Z	Z	L
11		0	Н	0	L	L	L	L	L	L	Z	Z	Z
12	Normal Operation H Input	0	Н	0	L	L	Н	Н	Н	Z	Z	Z	Z
13		0	Н	0	L	L	Н	L	Н	Z	Z	Z	L

o: VCC1 > UVLO, X: Don't care, Z: Hi-Z

9. Power supply startup / shutoff sequence



: Since the VCC2 to GND2 pin voltage is low and the output MOS does not turn ON, the output pins become Hi-Z conditions.

: Since the VCC1 pin voltage is low and the FLT output MOS does not turn ON, the output pins become Hi-Z conditions.

Figure 88. Power Supply Startup / Shutoff Sequence

Selection of Components Externally Connected

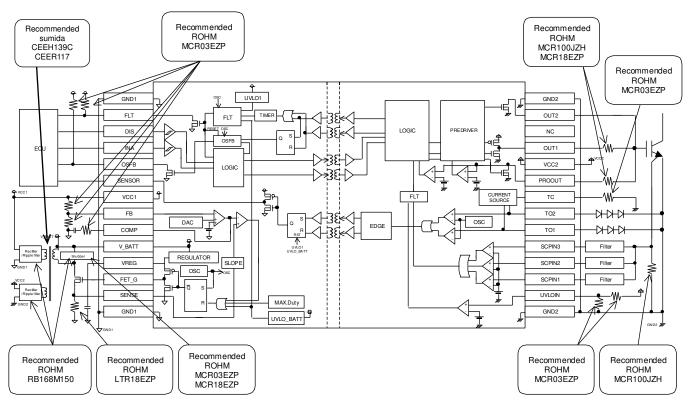


Figure 89. For using switching power supply controller

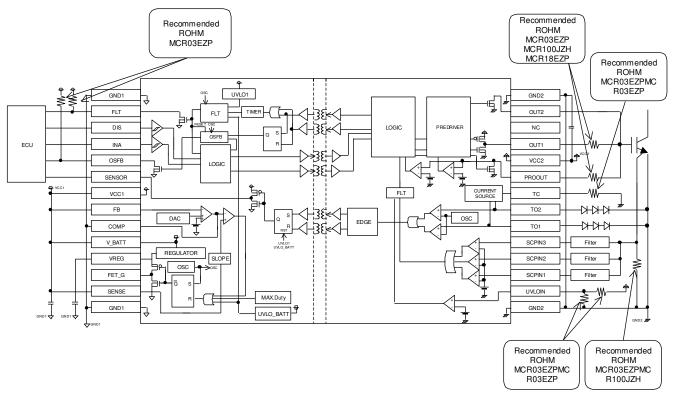


Figure 90. For no using switching power supply controller

Power Dissipation

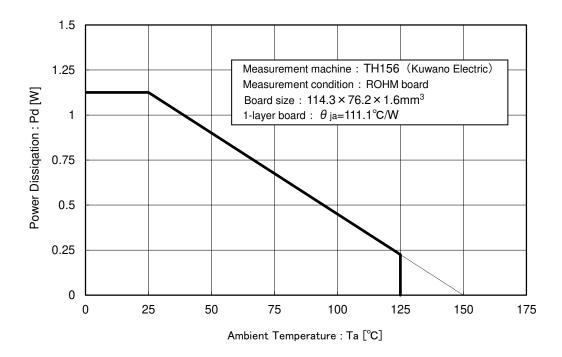


Figure 91. SSOP-B28W Power Dissipation Curve (Pd-Ta Curve)

Thermal Design

Please make sure that the IC's chip temperature Tj is not over 150°C, while considering the IC's power consumption (W), package power (Pd) and ambient temperature (Ta). When Tj=150°C is exceeded, the IC may malfunctions or some problems (ex. abnormal operation of various parasitic elements and increasing of leak current) may occur. Constant use under these circumstances leads to deterioration and eventually IC may destruct. Tjmax=150°C must be strictly obeyed under all circumstances.

I/O Equivalent Circuit

D: N	Pin Name	January Control of Familia plant Cine it Dia avenue	
Pin No.	Pin Function	Input Output Equivalent Circuit Diagram	
2	UVLOIN	VCC2 Internal pow er supply	
2	Output-side UVLO setting pin	GND2	
	SCPIN1	Internal pow er	
3	Short circuit current detection pin 1	VCC2 Internal pow er supply	
	SCPIN2	SCPIN1	
4	Short circuit current detection pin 2 SCPIN2 SCPIN3		
_	SCPIN3	GND2 O	
5	Short circuit current detection pin 3		
	TO1	VCC2 Internal pow er supply	
6	Constant current output pin / sensor voltage input pin 1	TO1 TO2	
7	TO2		
·	Constant current output pin / sensor voltage input pin 2	TCO P P P	
8	тс		
Ĵ	Constant current setting resistor connection pin	GND2O+++	

I/O Equivalent Circuit - continued

D: N	Pin Name	Input Output Equivalent Circuit Diagram		
Pin No.	Pin Function			
	OUT1	VCC2		
11	Output pin	OUT1 GND2		
9	PROOUT	Inter nal power supply		
	Soft turn-OFF pin /Gate voltage input pin	PROOL GND2		
13	OUT2	OUT2		
10	Output pin for Miller Clamp	GND2		
16	FLT			
16	Fault output pin	GND1		
40	OSFB			
19	Output state feedback output pin			
20	SENSOR	VCC1 SENSOR		
20	Temperature information output pin	GND1		

I/O Equivalent Circuit - continued

Dia Na	Pin Name	land Outrat Frankalant Circuit Bioman		
Pin No.	Pin Function	Input Output Equivalent Circuit Diagram		
17	DIS	VCC1 O		
,,	Input enabling signal input pin	GND1 O		
18	INA	VCC1		
10	Control input pin	GND1		
22	FB	V_BATT Internal pow er supply		
LL	Error amplifier inverting input pin for switching controller	GND1 O		
23	COMP	V_BATT Internal pow er supply COMP		
	Error amplifier output pin for switching controller	GND1		

I/O Equivalent Circuit - continued

Pin No.	Pin Name	Input Output Equivalent Circuit Diagram	
i iii ivo.	Pin Function		
25	VREG	Internal pow er supply	
20	Power supply pin for driving MOS FET of switching controller	VREG	
26	FET_G	FET_G	
20	MOS FET control pin for switching controller	— GND1	
27	SENSE	V_BATT Internal pow er supply	
21	Current feedback resistor connection pin for switching controller	SENSE W	

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes - continued

11. Unused Input Terminals

Input terminals of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input terminals should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

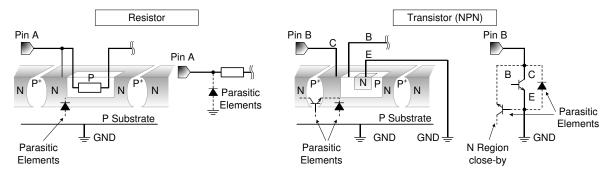
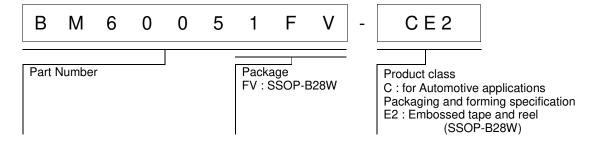


Figure 24. Example of monolithic IC structure

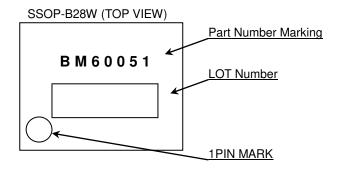
13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

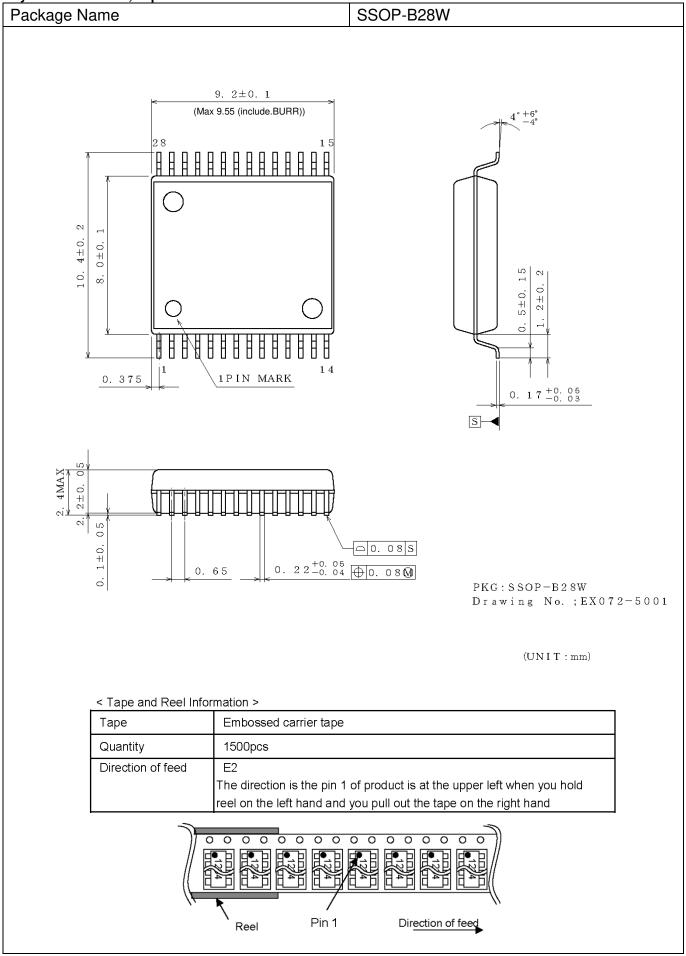
Ordering Information



Marking Diagram



Physical Dimension, Tape and Reel Information



Revision History

Date	Revision	Changes	
25.Apr.2014	001	New Release	
13.May.2015	002	P.1 Features Adding item (UL1577 Recognized) P.21,22 Typical Performance Curves Correcting mistakes	
25.Dec.2015	003	P.9 Adding UL1577 Rating Table	

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1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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ĺ	JAPAN	USA	EU	CHINA
	CLASSII	CLASSIII	CLASSIIb	OL ACOM
	CLASSIV		CLASSIII	CLASSII

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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
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